

WHAT IS CLAIMED IS:

1. A method of manufacturing a flat display provided with an array substrate comprising: a signal line layer and a scanning line layer longitudinally and transversely arranged on an insulating substrate; a plurality of pixel electrodes connected to respective intersections of said signal line layer and said scanning line layer via switching elements; an auxiliary capacity electrode electrically connected to said switching element via a semiconductor wiring; and an auxiliary capacity feeder disposed opposite to said auxiliary capacity electrode via an insulating layer, said method comprising a step of:

irradiating a portion of said semiconductor wiring with a laser light in such a manner that a laser intensity R (μJ) and a volume V (μm^3) of said wiring portion satisfy a relation of equation (1):

$$0.01 \times V + 0.6 < R < 0.1 \times V + 1.5 \dots (1)$$

2. The method of manufacturing a semiconductor circuit according to claim 1 wherein said laser light is applied from a direction of a surface opposite to a switching element forming surface of said insulating substrate.

3. The method of manufacturing the semiconductor circuit according to claim 1 wherein said switching element includes an active layer, and

said active layer, said semiconductor wiring and said auxiliary capacity electrode are formed in the same process.

4. The method of manufacturing the semiconductor circuit according to claim 3 wherein said active layer, said semiconductor wiring and said auxiliary capacity electrode are formed using polycrystalline silicon.

5. The method of manufacturing the semiconductor circuit according to claim 1, further comprising a step of selectively performing laser irradiation with respect to a defective pixel.

00667555-002300

7. A flat display provided with an array substrate comprising: signal lines and scanning lines longitudinally and transversely arranged on an insulating substrate; a plurality of pixel electrodes connected to respective intersections of said signal lines and said scanning lines via switching elements; a plurality of auxiliary capacity electrodes electrically connected to said switching elements; and an auxiliary capacity feeder disposed opposite to said auxiliary capacity electrode via an insulating layer, said flat display comprising:

a second wiring layer connected to said switching elements and said first wiring layer; and

wherein said first and second wiring layers are vertically formed on different layers.

9. The flat display according to claim 7 wherein said first wiring layer is formed on the same layer as that of said auxiliary capacity electrode.

11. The flat display according to claim 7 wherein a length

12. The flat display according to claim 7 wherein a channel area of said switching element, said auxiliary capacity electrode and said first wiring layer are formed using polycrystalline silicon.

forming a first wiring layer for connecting said switching elements to said auxiliary capacity electrode and said auxiliary capacity electrode;

forming a second wiring layer connected to said switching elements and said first wiring layer, an upper electrode connected to said pixel electrode, and a third wiring layer connected to said switching elements on the substrate top surface via a second insulating layer;

forming said pixel electrode on the top surface of said protective film via a third insulating film.

14. The method of manufacturing the flat display according to claim 13, further comprising a step of: irradiating, with a laser beam, a predetermined position of said first wiring layer corresponding to a short-circuit place between said auxiliary

